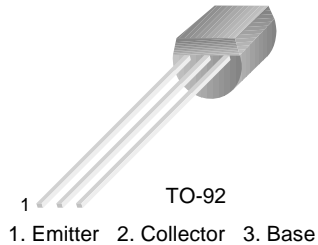


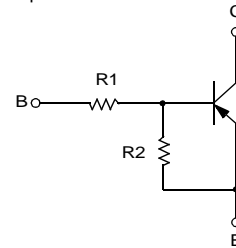
KSR2002

Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor ($R_1=10K\Omega$, $R_2=10K\Omega$)
- Complement to KSR1002



Equivalent Circuit



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-50	V
V_{CEO}	Collector-Emitter Voltage	-50	V
V_{EBO}	Emitter-Base Voltage	-10	V
I_C	Collector Current	-100	mA
P_C	Collector Power Dissipation	300	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C = -10\mu\text{A}$, $I_E = 0$	-50			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -100\mu\text{A}$, $I_B = 0$	-50			V
I_{CBO}	Collector Cut-off Current	$V_{CB} = -40\text{V}$, $I_E = 0$			-0.1	μA
h_{FE}	DC Current Gain	$V_{CE} = -5\text{V}$, $I_C = -5\text{mA}$	30			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -10\text{mA}$, $I_B = -0.5\text{mA}$			-0.3	V
f_T	Current Gain Bandwidth Product	$V_{CE} = -5\text{mA}$, $I_C = -10\text{V}$		200		MHz
C_{ob}	Output Capacitance	$V_{CB} = -10\text{V}$, $I_E = 0$ $f = 1.0\text{MHz}$		5.5		pF
$V_I(\text{off})$	Input Off Voltage	$V_{CE} = -5\text{V}$, $I_C = -100\mu\text{A}$	-0.5			V
$V_I(\text{on})$	Input On Voltage	$V_{CE} = -0.3\text{V}$, $I_C = -10\text{mA}$			-3	V
R_1	Input Resistor		7	10	13	$K\Omega$
R_1/R_2	Resistor Ratio		0.9	1	1.1	

Typical Characteristics

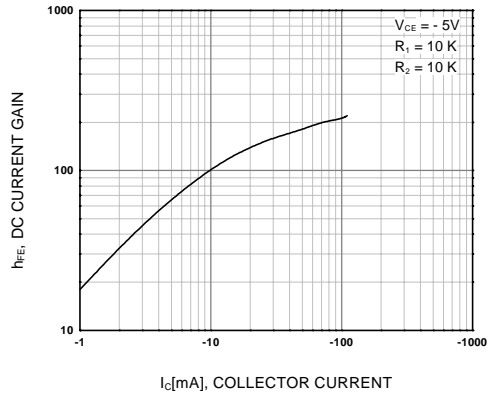


Figure 1. DC current Gain

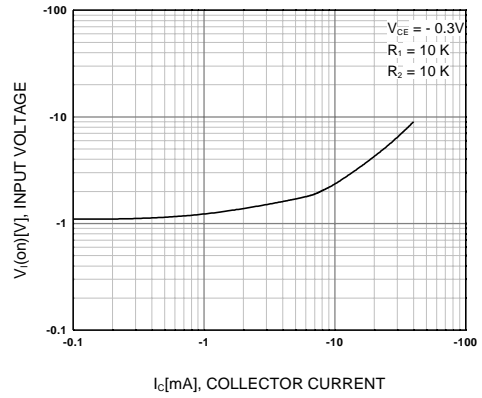


Figure 2. Input On Voltage

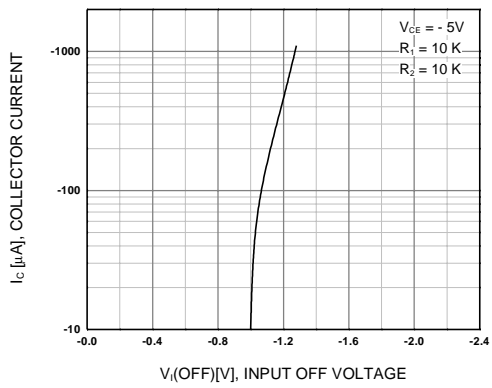


Figure 3. Input Off Voltage

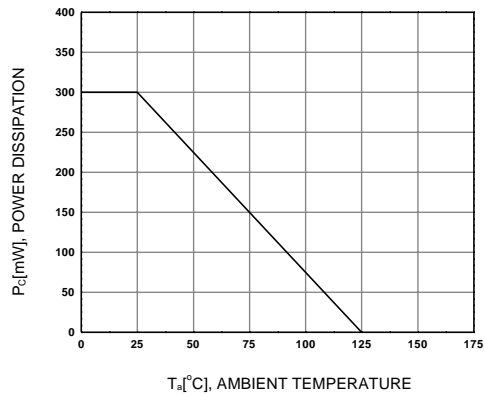
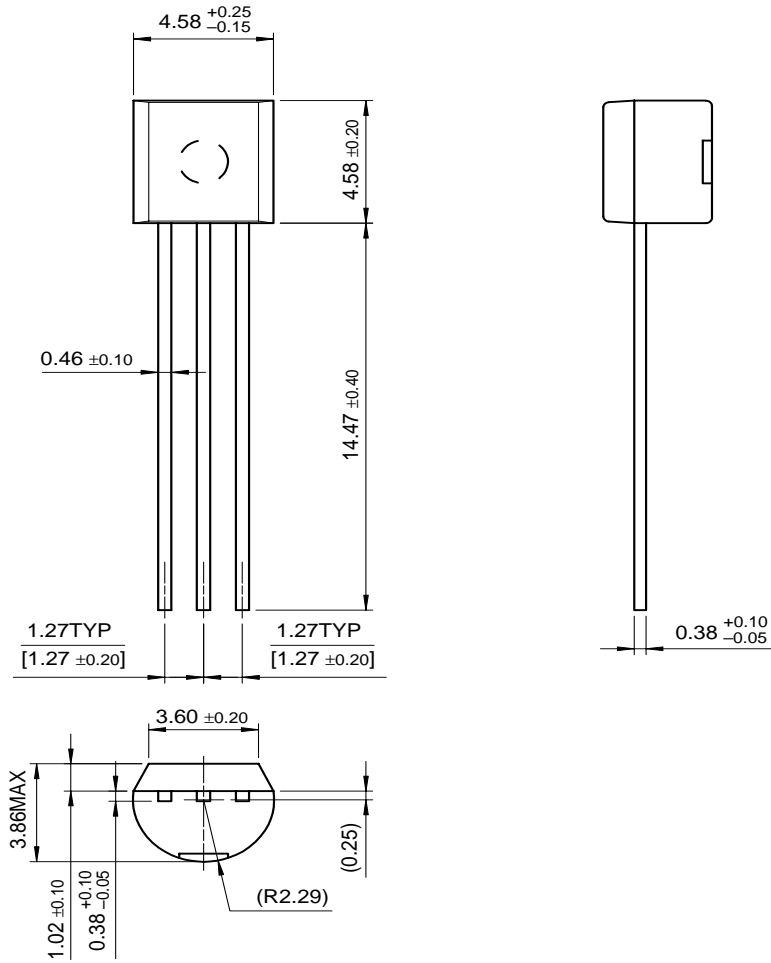


Figure 4. Power Derating

Package Dimensions

TO-92



Dimensions in Millimeters

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